Docket No. 0756-2306

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Patent Application of:

Taketomi ASAMI et al.

Serial No. 09/842,315

Filed: 04/26/2001

For: MANUFACTURING METHOD FOR

SEMICONDUCTOR DEVICE

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Group Art Unit: 2813

Examiner: David S. Blum

Confirmation No. 5664

**CERTIFICATE OF MAILING** 

I hereby certify that this correspondence is being deposited with the United States Postal Service with sufficient postage as First Class Mail in an envelop address to: Commissioner for Patents, Washington, D.C. 20231, on May 17, 2002.

Ava M. Dixon

A method for manufacturing a semiconductor device

## **AMENDMENT**

Commissioner for Patents Washington, D.C. 20231

Sir:

In response to the Office Action mailed January 17, 2002, please amend the above identified application as follows.

## **IN THE CLAIMS:**

Please amend claims 1-14 as follows:

(Amended)

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SUB /comprising:

the first step of forming a semiconductor film;

the second step of etching the semiconductor film to remove contaminant impurities on a surface of said semiconductor film; and

the third step of forming a gate insulating film in contact with said semiconductor film after said second step;

48 (1. E.VE (1958-44), (1901)[17] (1964-55);

71 F04 38 - 253, 31 - 253, 31 - 253, 31 - 253, 31 - 253, 31 - 353,